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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/618,616	07/15/2003	Tohru Ozaki	240324US-2 TTC DIV	5367
22850	7590 05/19/2005		EXAMINER ·	
OBLON, SPIVAK, MCCLELLAND, MAIER & NEUSTADT, P.C. 1940 DUKE STREET ALEXANDRIA, VA 22314			ECKERT II, GEORGE C	
			ART UNIT	PAPER NUMBER
			2815	

DATE MAILED: 05/19/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

AK

	Application No.	Applicant(s)			
	10/618,616	OZAKI ET AL.			
Office Action Summary	Examiner	Art Unit			
	George C. Eckert II	2815			
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply					
A SHORTENED STATUTORY PERIOD FOR REPITHE MAILING DATE OF THIS COMMUNICATION - Extensions of time may be available under the provisions of 37 CFR 1 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a re - If NO period for reply is specified above, the maximum statutory period. - Failure to reply within the set or extended period for reply will, by statu Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	136(a). In no event, however, may a reply be tir ply within the statutory minimum of thirty (30) day d will apply and will expire SIX (6) MONTHS from te, cause the application to become ABANDONE	nely filed s will be considered timely. the mailing date of this communication. (D) (35 U.S.C. § 133).			
Status					
1)⊠ Responsive to communication(s) filed on <u>02</u>	<u>March 2005</u> .				
2a)⊠ This action is FINAL . 2b)☐ Th	is action is non-final.				
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is					
closed in accordance with the practice under	Ex parte Quayle, 1935 C.D. 11, 4	53 O.G. 213.			
Disposition of Claims					
4)⊠ Claim(s) <u>30 and 31</u> is/are pending in the application.					
4a) Of the above claim(s) is/are withdrest is/are withdrest is/are allowed. 5) Claim(s) is/are allowed. 6) Claim(s) 30 and 31 is/are rejected. 7) Claim(s) is/are objected to. 8) Claim(s) are subject to restriction and/	awn from consideration.				
Application Papers					
9) The specification is objected to by the Examination 10) The drawing(s) filed on is/are: a) acceptant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the Examination is objected to be a by the Examination is objected to by the Examination is objected to be a by the Examination is objected to be a by the Examination is objected to be a by the Exami	ccepted or b) objected to by the edrawing(s) be held in abeyance. Se ction is required if the drawing(s) is ob	e 37 CFR 1.85(a). jected to. See 37 CFR 1.121(d).			
Priority under 35 U.S.C. § 119					
12) Acknowledgment is made of a claim for foreig a) All b) Some * c) None of: 1. Certified copies of the priority documer 2. Certified copies of the priority documer 3. Copies of the certified copies of the pri application from the International Bures * See the attached detailed Office action for a list	nts have been received. nts have been received in Applicati ority documents have been receive au (PCT Rule 17.2(a)).	ion No ed in this National Stage			
Attachment(s) 1) Notice of References Cited (PTO-892)	4) 🔲 Interview Summary	(PTO-413)			
2) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08 Paper No(s)/Mail Date 3/2/05.	Paper No(s)/Mail D				
U.S. Patent and Trademark Office PTOL-326 (Rev. 1-04) Office A	Action Summary Pa	art of Paper No./Mail Date 05122005			

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Response to Amendment

1. Applicant's amendment dated March 2, 2005 in which claims 30 and 31 were amended has been entered.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 2. Claims 30 and 31 are rejected under 35 U.S.C. 102(e) as being anticipated by US 6,366,488 to Zambrano et al. Zambrano et al. teach, with reference to figures 1 and 4 a method of making a memory device comprising:

forming a cell transistor (e.g. 2, fig. 4) including first and second impurity diffused regions 7, a gate 9 between the impurity regions on the substrate 6;

forming a block transistor (3, fig. 1)including third and fourth impurity regions and a gate there between (inherent) and adjoined to the cell transistor (see fig. 1 showing the block transistor adjoining the memory transistors 2, col. 2, lines 54-56);

forming a lower electrode 11 over the cell and block transistors and connected to the first impurity region 7;

forming a ferroelectric 12 on the lower electrode 11;

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forming an upper electrode 13 on the ferroelectric and into a first and second upper electrode (as seen by the upper electrode's T shape, col. 3, lines 35-37);

forming the lower electrode and ferroelectric layer into a capacitor shape (as seen in figure 4, the lower electrode and ferroelectric serve as components of a capacitor);

forming a wiring layer 8 connecting between the first upper electrode and the second impurity diffused region; and

covering the second upper electrode with an insulating layer 14 such that the second upper electrode is insulated from the impurity diffused regions by the insulating layer and the ferroelectric layer (col. 3, lines 42-44).

3. Claims 30 and 31 are rejected under 35 U.S.C. 102(b) as being anticipated by A Sub-40ns Chain FRAM Architecture with 7-ns Cell-Plate-Line Drive to Takashima et al. Takashima et al disclose in figure 5b and in the paragraph bridging pages 1559-60 a method of making a device comprising:

forming a cell transistor including impurity diffused regions and a gate there between (any of transistors WLs);

forming a block selecting transistor adjoining the cell transistor (see fig. 5a, "Block Select");

forming a lower electrode over the transistors and connected to the first impurity region of the cell transistor, forming a ferroelectric layer over the lower electrode, forming an upper electrode comprised of two parts over the ferroelectric layer and forming a wiring layer to connect the first upper electrode to the second impurity region; and

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covering the second upper electrode with insulating layer such that the second upper electrode is insulated from the diffusion regions by the insulation layer and the ferroelectric layer.

4. Claim 30 is rejected under 35 U.S.C. 102(e) as being clearly anticipated by US 6,759,251 to Ozaki. The applied reference has a common inventor with the instant application. Based upon the earlier effective U.S. filing date of the reference, it constitutes prior art under 35 U.S.C. 102(e). This rejection under 35 U.S.C. 102(e) might be overcome either by a showing under 37 CFR 1.132 that any invention disclosed but not claimed in the reference was derived from the inventor of this application and is thus not the invention "by another," or by an appropriate showing under 37 CFR 1.131. Ozaki shows in figures 2A-G the instantly claimed method.

Response to Arguments

Applicant's arguments filed March 2, 2005 have been fully considered but they are not persuasive. As part of the argument, Applicant explains the present invention including the purpose of the second upper electrode and points to instant figure 1 which shows a second upper electrode 25 having the purpose of reducing micro-loading effects. Upper electrode 25 is insulated from and not electrically connected to any diffusion region. However, the claim language is not so narrowly construed. Rather, the claim merely cites a second upper electrode, now covered with insulation, such that the insulation and ferroelectric layer isolate the electrode from the diffusion regions. This limitation is taught by the prior art. Zambrano's insulation 14 covers the first and second upper electrodes (the right and left arms of the T-shaped upper

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electrode 13) and, with the ferroelectric layer 12, isolates the upper electrode 13, from the diffusion regions 7. Takashima and Ozaki '251 also teach the new limitation in that the upper electrode in both references is insulated from, which is to say isolated from, the diffusion regions. Despite arguments to the contrary, the amended limitation requires no more than the isolation already taught in the art. As such, the arguments are not persuasive.

Conclusion

6. THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to George C. Eckert II whose telephone number is (571) 272-1728.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Tom Thomas can be reached on (571) 272-1664. The fax phone number for the

organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

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